

TQC2019B

High Frequency, High Temp, One-Output Clock Generator

TOKYO QUARTZ CO.,LTD

Features

- Frequencies between 115.194001 MHz to 137 MHz accurate to 6 decimal places
- Operating temperature from -40°C to 125°C. For -55°C option, refer to [TQC2020](#) and [TQC2021](#)
- Supply voltage of 1.8V or 2.5V to 3.3V
- Excellent total frequency stability as low as ± 20 ppm
- Low power consumption of 4.9 mA typical at 1.8V
- LVCMOS/LVTTL compatible output
- 5-pin SOT23-5 package: 2.9mm x 2.8mm
- RoHS and REACH compliant, Pb-free, Halogen-free and Antimony-free
- For AEC-Q100 clock generators, refer to [TQC2024](#) and [TQC2025](#)

Applications

- Industrial, medical, avionics and other high temperature applications
- Industrial sensors, PLC, motor servo, outdoor networking equipment, medical video cam, asset tracking systems, etc.



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Electrical Specifications

Table 1. Electrical Characteristics

All Min and Max limits are specified over temperature and rated operating voltage with 15 pF output load unless otherwise stated. Typical values are at 25°C and nominal supply voltage.

| Parameters | Symbol | Min. | Typ. | Max. | Unit | Condition |
|---|-------------------|------------|------|------|-----------------|---|
| Frequency Range | | | | | | |
| Output Frequency Range | f | 115.194001 | – | 137 | MHz | Refer to Table 14 for the exact list of supported frequencies list of supported frequencies |
| Frequency Stability and Aging | | | | | | |
| Frequency Stability | F _{stab} | -20 | – | +20 | ppm | Inclusive of Initial tolerance at 25°C, 1st year aging at 25°C, and variations over operating temperature, rated power supply voltage and load (15 pF \pm 10%). |
| | | -25 | – | +25 | ppm | |
| | | -30 | – | +30 | ppm | |
| | | -50 | – | +50 | ppm | |
| Operating Temperature Range | | | | | | |
| Operating Temperature Range (ambient) | T _{use} | -40 | – | +105 | °C | Extended Industrial |
| | | -40 | – | +125 | °C | Automotive |
| Supply Voltage and Current Consumption | | | | | | |
| Supply Voltage | V _{dd} | 1.62 | 1.8 | 1.98 | V | |
| | | 2.25 | 2.5 | 2.75 | V | |
| | | 2.52 | 2.8 | 3.08 | V | |
| | | 2.7 | 3.0 | 3.3 | V | |
| | | 2.97 | 3.3 | 3.63 | V | |
| | | 2.25 | – | 3.63 | V | |
| Current Consumption | I _{dd} | – | 6.2 | 8 | mA | No load condition, f = 125 MHz, V _{dd} = 2.8V, 3.0V or 3.3V |
| | | – | 5.4 | 7 | mA | No load condition, f = 125 MHz, V _{dd} = 2.5V |
| | | – | 4.9 | 6 | mA | No load condition, f = 125 MHz, V _{dd} = 1.8V |
| OE Disable Current | I _{od} | – | – | 4.8 | mA | V _{dd} = 2.5V to 3.3V, OE = Low, Output in high Z state. |
| | | – | – | 4.5 | mA | V _{dd} = 1.8V, OE = Low, Output in high Z state. |
| Standby Current | I _{std} | – | 2.6 | 8.5 | μ A | V _{dd} = 2.8V to 3.3V, \overline{ST} = Low, Output is weakly pulled down |
| | | – | 1.4 | 5.5 | μ A | V _{dd} = 2.5V, \overline{ST} = Low, Output is weakly pulled down |
| | | – | 0.6 | 4.0 | μ A | V _{dd} = 1.8V, \overline{ST} = Low, Output is weakly pulled down |
| LVCMOS Output Characteristics | | | | | | |
| Duty Cycle | DC | 45 | – | 55 | % | All V _{dds} |
| Rise/Fall Time | Tr, Tf | – | 1.0 | 2.0 | ns | V _{dd} = 2.5V, 2.8V, 3.0V or 3.3V, 20% - 80% |
| | | – | 1.3 | 2.5 | ns | V _{dd} = 1.8V, 20% - 80% |
| | | – | 1.0 | 3 | ns | V _{dd} = 2.25V - 3.63V, 20% - 80% |
| Output High Voltage | VOH | 90% | – | – | V _{dd} | IOH = -4 mA (V _{dd} = 3.0V or 3.3V) IOH = -3 mA (V _{dd} = 2.8V or 2.5V) IOH = -2 mA (V _{dd} = 1.8V) |
| Output Low Voltage | VOL | – | – | 10% | V _{dd} | IOL = 4 mA (V _{dd} = 3.0V or 3.3V) IOL = 3 mA (V _{dd} = 2.8V or 2.5V) IOL = 2 mA (V _{dd} = 1.8V) |

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Table 1. Electrical Characteristics (continued)

| Parameters | Symbol | Min. | Typ. | Max. | Unit | Condition |
|----------------------------------|---------------------|------|------|------|-----------------|---|
| Input Characteristics | | | | | | |
| Input High Voltage | V _{IH} | 70% | – | – | V _{dd} | Pin 1, OE or \overline{ST} |
| Input Low Voltage | V _{IL} | – | – | 30% | V _{dd} | Pin 1, OE or \overline{ST} |
| Input Pull-up Impedance | Z _{in} | 50 | 87 | 150 | k Ω | Pin 1, OE logic high or logic low, or \overline{ST} logic high |
| | | 2 | – | – | M Ω | Pin 1, \overline{ST} logic low |
| Startup and Resume Timing | | | | | | |
| Startup Time | T _{start} | – | – | 5 | ms | Measured from the time V _{dd} reaches its rated minimum value |
| Enable/Disable Time | T _{oe} | – | – | 130 | ns | f = 115.194001 MHz. For other frequencies, T _{oe} = 100 ns + 3 * clock periods |
| Resume Time | T _{resume} | – | – | 5 | ms | Measured from the time \overline{ST} pin crosses 50% threshold |
| Jitter | | | | | | |
| RMS Period Jitter | T _{jitt} | – | 1.6 | 2.5 | ps | f = 125 MHz, V _{dd} = 2.5V, 2.8V, 3.0V or 3.3V |
| | | – | 1.8 | 3 | ps | f = 125 MHz, V _{dd} = 1.8V |
| Peak-to-peak Period Jitter | T _{pk} | – | 12 | 20 | ps | f = 125 MHz, V _{dd} = 2.5V, 2.8V, 3.0V or 3.3V |
| | | – | 14 | 30 | ps | f = 125 MHz, V _{dd} = 1.8V |
| RMS Phase Jitter (random) | T _{phj} | – | 0.5 | 0.8 | ps | f = 125 MHz, Integration bandwidth = 900 kHz to 7.5 MHz |
| | | – | 1.3 | 2 | ps | f = 125 MHz, Integration bandwidth = 12 kHz to 20 MHz |

Table 2. Pin Description

| Pin | Symbol | Functionality | |
|-----|-------------------------|---------------|---|
| 1 | GND | Power | Electrical ground |
| 2 | NC | No Connect | No connect |
| 3 | OE/ \overline{ST} /NC | Output Enable | H ^[1] : specified frequency output L: output is high impedance. Only output driver is disabled. |
| | | Standby | H or Open ^[1] : specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I _{std} . |
| | | No Connect | Any voltage between 0 and V _{dd} or Open ^[1] : Specified frequency output. Pin 3 has no function. |
| 4 | VDD | Power | Power supply voltage ^[2] |
| 5 | OUT | Output | Oscillator output |

Notes:

- In OE or \overline{ST} mode, a pull-up resistor of 10 k Ω or less is recommended if pin 3 is not externally driven. If pin 3 needs to be left floating, use the NC option.
- A capacitor of value 0.1 μ F or higher between V_{dd} and GND is required.

Top View

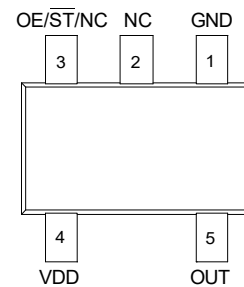


Figure 1. Pin Assignments

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Table 3. Absolute Maximum Limits

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

| Parameter | Min. | Max. | Unit |
|--|------|------|------|
| Storage Temperature | -65 | 150 | °C |
| Vdd | -0.5 | 4 | V |
| Electrostatic Discharge | – | 2000 | V |
| Soldering Temperature (follow standard Pb free soldering guidelines) | – | 260 | °C |
| Junction Temperature ^[3] | – | 150 | °C |

Note:

3. Exceeding this temperature for extended period of time may damage the device.

Table 4. Thermal Consideration^[4]

| Package | θ_{JA} , 4 Layer Board (°C/W) | θ_{JC} , Bottom (°C/W) |
|---------|---|----------------------------------|
| SOT23-5 | 421 | 175 |

Note:

4. Refer to JESD51 for θ_{JA} and θ_{JC} definitions, and reference layout used to determine the θ_{JA} and θ_{JC} values in the above table.

Table 5. Maximum Operating Junction Temperature^[5]

| Max Operating Temperature (ambient) | Maximum Operating Junction Temperature |
|-------------------------------------|--|
| 105°C | 115°C |
| 125°C | 135°C |

Note:

5. Datasheet specifications are not guaranteed if junction temperature exceeds the maximum operating junction temperature.

Table 6. Environmental Compliance

| Parameter | Condition/Test Method |
|----------------------------|--------------------------|
| Mechanical Shock | MIL-STD-883F, Method2002 |
| Mechanical Vibration | MIL-STD-883F, Method2007 |
| Temperature Cycle | JESD22, Method A104 |
| Solderability | MIL-STD-883F, Method2003 |
| Moisture Sensitivity Level | MSL1 @ 260°C |

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Test Circuit and Waveform^[6]

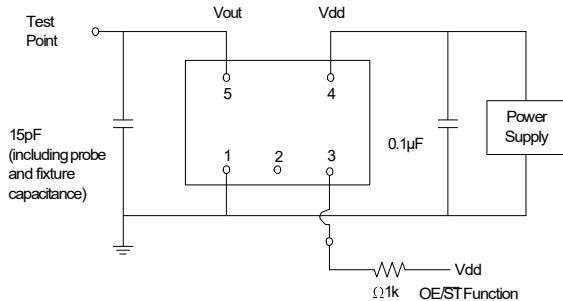


Figure 2. Test Circuit

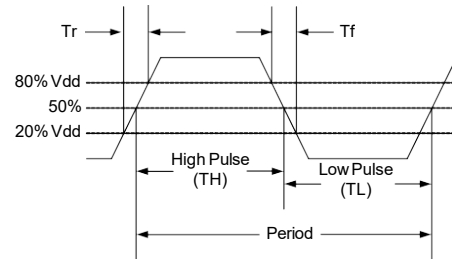


Figure 3. Output Waveform

Note:

6. Duty Cycle is computed as Duty Cycle = TH/Period.

Timing Diagrams

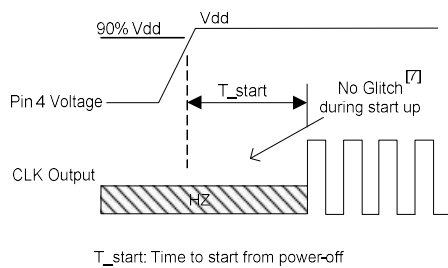


Figure 4. Startup Timing (OE/ST Mode)

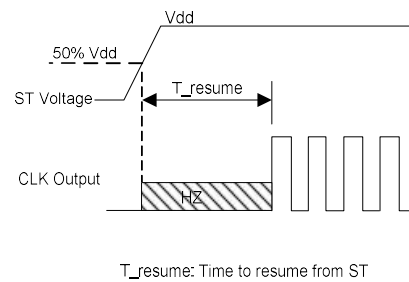


Figure 5. Standby Resume Timing (ST Mode Only)

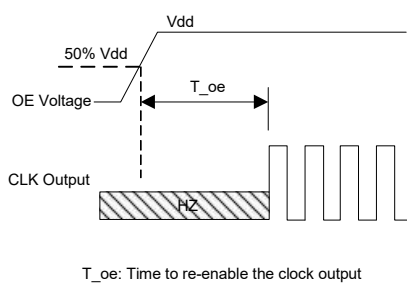


Figure 6. OE Enable Timing (OE Mode Only)

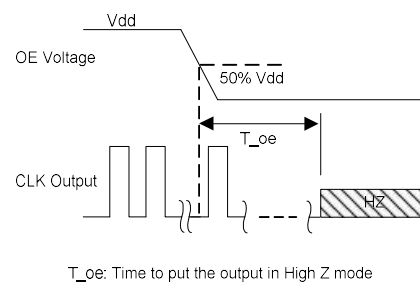


Figure 7. OE Disable Timing (OE Mode Only)

Note:

7. TQC2019 has “no runt” pulses and “no glitch” output during startup or resume.

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Performance Plots^[8]

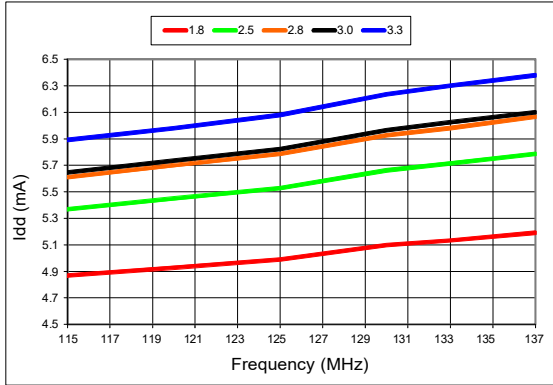


Figure 8. Idd vs Frequency

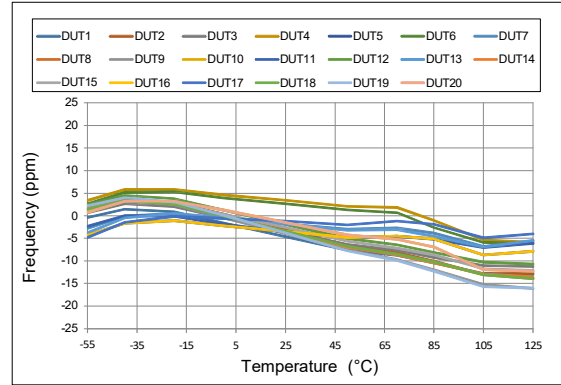


Figure 9. Frequency vs Temperature

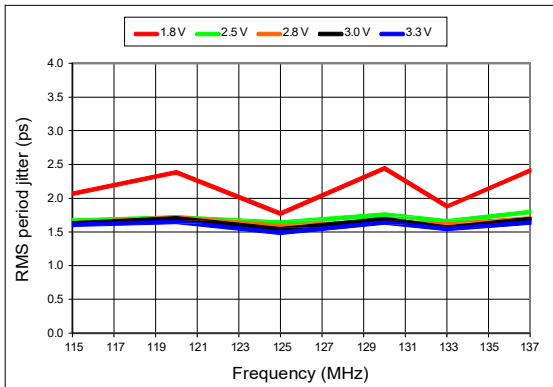


Figure 10. RMS Period Jitter vs Frequency

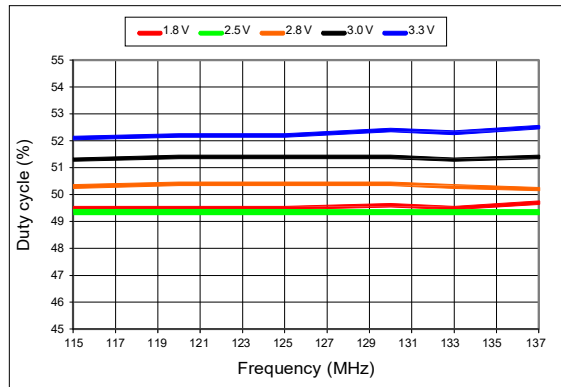


Figure 11. Duty Cycle vs Frequency

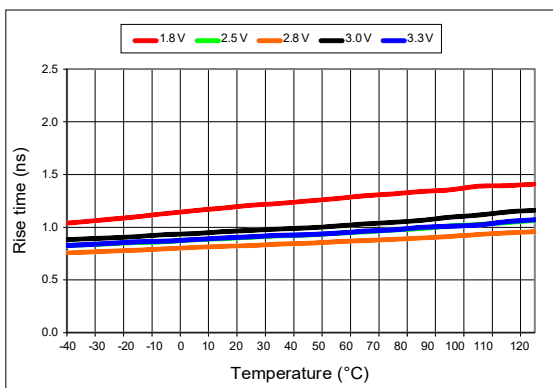


Figure 12. 20%-80% Rise Time vs Temperature (125 MHz Output)

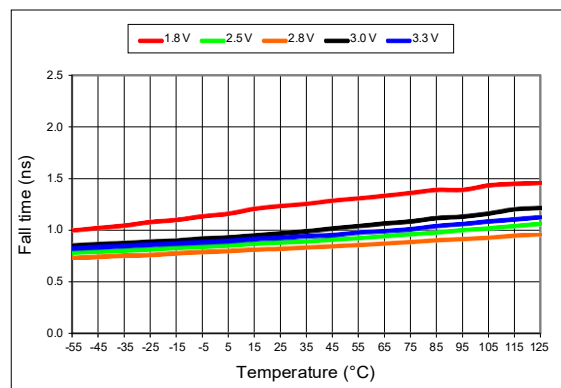


Figure 13. 20%-80% Fall Time vs Temperature (125 MHz Output)

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Performance Plots^[8]

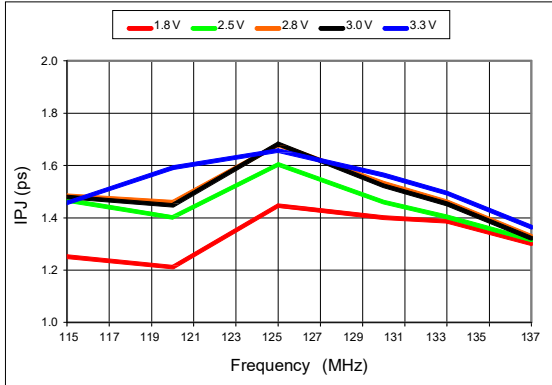


Figure 14. RMS Integrated Phase Jitter Random (12 kHz to 20 MHz) vs Frequency^[9]

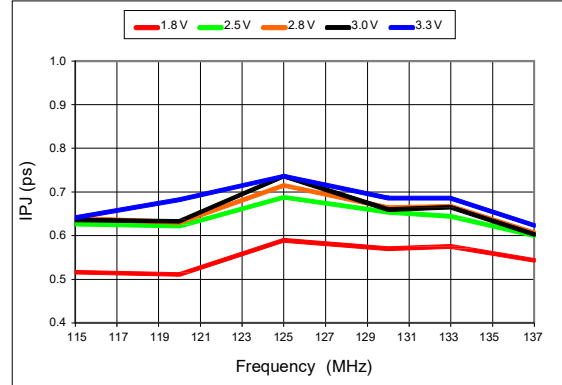


Figure 15. RMS Integrated Phase Jitter Random (900 kHz to 20 MHz) vs Frequency^[9]

Notes:

- 8. All plots are measured with 15 pF load at room temperature, unless otherwise stated.
- 9. Phase noise plots are measured with Agilent E5052B signal source analyzer.

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Programmable Drive Strength

The TQC2019 includes a programmable drive strength feature to provide a simple, flexible tool to optimize the clock rise/fall time for specific applications. Benefits from the programmable drive strength feature are:

- Improves system radiated electromagnetic interference (EMI) by slowing down the clock rise/fall time.
- Improves the downstream clock receiver's (RX) jitter by decreasing (speeding up) the clock rise/fall time.
- Ability to drive large capacitive loads while maintaining full swing with sharp edge rates.

For more detailed information about rise/fall time control and drive strength selection, see the TQC Application Notes section:

EMI Reduction by Slowing Rise/Fall Time

Figure 16 shows the harmonic power reduction as the rise/fall times are increased (slowed down). The rise/fall times are expressed as a ratio of the clock period. For the ratio of 0.05, the signal is very close to a square wave. For the ratio of 0.45, the rise/fall times are very close to near-triangular waveform. These results, for example, show that the 11th clock harmonic can be reduced by 35 dB if the rise/fall edge is increased from 5% of the period to 45% of the period.

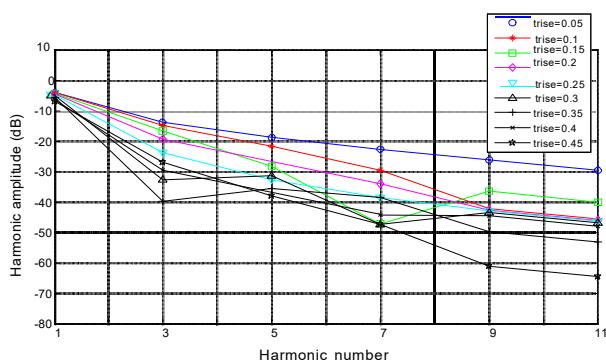


Figure 16. Harmonic EMI reduction as a Function of Slower Rise/Fall Time

Jitter Reduction with Faster Rise/Fall Time

Power supply noise can be a source of jitter for the downstream chipset. One way to reduce this jitter is to speed up the rise/fall time of the input clock. Some chipsets may also require faster rise/fall time in order to reduce their sensitivity to this type of jitter. Refer to the Rise/Fall Time Tables (Table 7 to Table 11) to determine the proper drive strength.

High Output Load Capability

The rise/fall time of the input clock varies as a function of the actual capacitive load the clock drives. At any given drive strength, the rise/fall time becomes slower as the output load increases. As an example, for a 3.3V TQC2019 device with default drive strength setting, the typical rise/fall time is 0.46 ns for 5 pF output load. The typical rise/fall time slows down to 1 ns when the output load increases to 15 pF. One can choose to speed up the rise/fall time to 0.72 ns by then increasing the driven strength setting on the TQC2019 to "F."

The TQC2019 can support up to 30 pF in maximum capacitive loads with up to 3 additional drive strength settings. Refer to the Rise/Fall Time Tables (Table 7 to 11) to determine the proper drive strength for the desired combination of output load vs. rise/fall time.

TQC2019 Drive Strength Selection

Tables 7 through 11 define the rise/fall time for a given capacitive load and supply voltage.

1. Select the table that matches the TQC2019 nominal supply voltage (1.8V, 2.5V, 2.8V, 3.0V, 3.3V).
2. Select the capacitive load column that matches the application requirement (5 pF to 30 pF)
3. Under the capacitive load column, select the desired rise/fall times.
4. The left-most column represents the part number code for the corresponding drive strength.
5. Add the drive strength code to the part number for ordering purposes.

Calculating Maximum Frequency

Based on the rise and fall time data given in Tables 7 through 11, the maximum frequency the oscillator can operate with guaranteed full swing of the output voltage over temperature can be calculated as follows:

$$\text{Max Frequency} = \frac{1}{5 \times \text{Trf}_{20/80}}$$

where Trf_{20/80} is the typical value for 20%-80% rise/fall time.

Example 1

Calculate f_{MAX} for the following condition:

- V_{dd} = 3.3V (Table 11)
- Capacitive Load: 30 pF
- Desired Tr/f time = 1.46 ns (rise/fall time part number code = U)

Part number for the above example:

TQC2019BIU12-33E-136.986300



Drive strength code is inserted here. Default setting is "-"

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Rise/Fall Time (20% to 80%) vs C_{LOAD} Tables

Table 7. V_{dd} = 1.8V Rise/Fall Times for Specific C_{LOAD}

| Rise/Fall Time Typ (ns) | | | |
|------------------------------------|------|-------|-------|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF |
| T | 0.93 | n/a | n/a |
| E | 0.78 | n/a | n/a |
| U | 0.70 | 1.48 | n/a |
| F or "-": default | 0.65 | 1.30 | n/a |

Table 8. V_{dd} = 2.5V Rise/Fall Times for Specific C_{LOAD}

| Rise/Fall Time Typ (ns) | | | |
|------------------------------------|------|-------|-------|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF |
| R | 1.45 | n/a | n/a |
| B | 1.09 | n/a | n/a |
| T | 0.62 | 1.28 | n/a |
| E | 0.54 | 1.00 | n/a |
| U or "-": default | 0.43 | 0.96 | n/a |
| F | 0.34 | 0.88 | n/a |

Table 9. V_{dd} = 2.8V Rise/Fall Times for Specific C_{LOAD}

| Rise/Fall Time Typ (ns) | | | |
|------------------------------------|------|-------|-------|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF |
| R | 1.29 | n/a | n/a |
| B | 0.97 | n/a | n/a |
| T | 0.55 | 1.12 | n/a |
| E | 0.44 | 1.00 | n/a |
| U or "-": default | 0.34 | 0.88 | n/a |
| F | 0.29 | 0.81 | 1.48 |

Table 10. V_{dd} = 3.0V Rise/Fall Times for Specific C_{LOAD}

| Rise/Fall Time Typ (ns) | | | |
|------------------------------------|------|-------|-------|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF |
| R | 1.22 | n/a | n/a |
| B | 0.89 | n/a | n/a |
| T or "-": default | 0.51 | 1.00 | n/a |
| E | 0.38 | 0.92 | n/a |
| U | 0.30 | 0.83 | n/a |
| F | 0.27 | 0.76 | 1.39 |

Table 11. V_{dd} = 3.3V Rise/Fall Times for Specific C_{LOAD}

| Rise/Fall Time Typ (ns) | | | |
|------------------------------------|------|-------|-------|
| Drive Strength \ C _{LOAD} | 5 pF | 15 pF | 30 pF |
| R | 1.16 | n/a | n/a |
| B | 0.81 | n/a | n/a |
| T or "-": default | 0.46 | 1.00 | n/a |
| E | 0.33 | 0.87 | n/a |
| U | 0.28 | 0.79 | 1.46 |
| F | 0.25 | 0.72 | 1.31 |

Note:

10. "n/a" in Table 7 to Table 11 indicates that the resulting rise/fall time from the respective combination of the drive strength and output load does not provide rail-to-rail swing and is not available.

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Pin 3 Configuration Options (OE, \overline{ST} , or NC)

Pin 3 of the TQC2019 can be factory-programmed to support three modes: Output Enable (OE), standby (\overline{ST}) or No Connect (NC). These modes can also be programmed with the Time Machine using field programmable devices.

Output Enable (OE) Mode

In the OE mode, applying logic Low to the OE pin only disables the output driver and put TQC in Hi-Z mode. The core of the device continues to operate normally. Power consumption is reduced due to the inactivity of the output. When the OE pin is pulled High, the output is typically enabled in $<1\mu s$.

Standby (\overline{ST}) Mode

In the \overline{ST} mode, a device enters into the standby mode when Pin 3 pulled Low. All internal circuits of the device are turned off. The current is reduced to a standby current, typically in the range of a few μA . When \overline{ST} is pulled High, the device goes through the “resume” process, which can take up to 5 ms.

No Connect (NC) Mode

In the NC mode, the device always operates in its normal mode and outputs the specified frequency regardless of the logic level on pin 3.

Table 12 below summarizes the key relevant parameters in the operation of the device in OE, \overline{ST} , or NC mode.

Table 12. OE vs. \overline{ST} vs. NC

| | OE | \overline{ST} | NC |
|---|--------|-----------------|------|
| Active current 125 MHz (max, 1.8V) | 6 mA | 6 mA | 6 mA |
| OE disable current (max, 1.8V) | 4.5 mA | N/A | N/A |
| Standby current (typical 1.8V) | N/A | 0.6 μA | N/A |
| OE enable time at 125 MHz (max) | 130 ns | N/A | N/A |
| Resume time from standby (max, all frequency) | N/A | 5 ms | N/A |
| Output driver in OE disable/standby mode | High Z | weak pull-down | N/A |

Output on Startup and Resume

The TQC2019 comes with gated output. Its clock output is accurate to the rated frequency stability within the first pulse from initial device startup or resume from the standby mode.

In addition, the TQC2019 has “no runt” pulses, and “no glitch” output during startup or resume as shown in the waveform captures in Figure 17 and Figure 18.

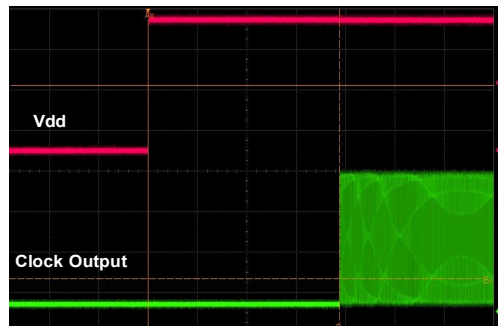


Figure 17. Startup Waveform vs. Vdd

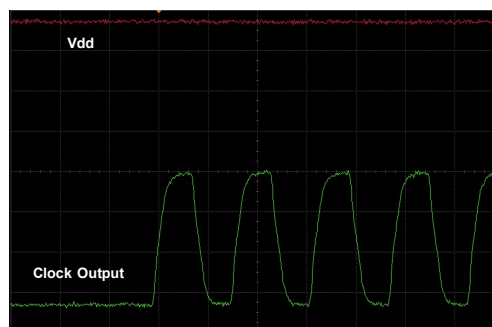


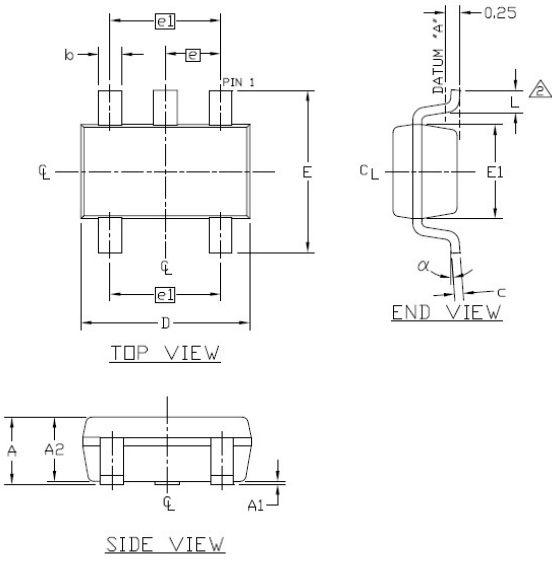
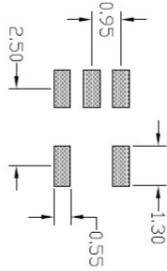
Figure 18. Startup Waveform vs. Vdd (Zoomed-in View of Figure 17)

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Dimensions and Patterns

| Package Size – Dimensions (Unit: mm) ^[11] | Recommended Land Pattern (Unit: mm) ^[12] |
|--|---|
| <p>2.90 x 2.80 mm SOT23-5</p>  <p>TOP VIEW</p> <p>END VIEW</p> <p>SIDE VIEW</p> |  <p>END VIEW</p> |

Notes:

- 11. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
- 12. A capacitor value of 0.1 μ F between Vdd and GND is required

Table 13. Dimension Table

| Symbol | Min. | Nom. | Max. |
|----------|-----------|------|------|
| A | 0.90 | 1.27 | 1.45 |
| A1 | 0.00 | 0.07 | 0.15 |
| A2 | 0.90 | 1.20 | 1.30 |
| b | 0.30 | 0.35 | 0.50 |
| c | 0.14 | 0.15 | 0.20 |
| D | 2.75 | 2.90 | 3.05 |
| E | 2.60 | 2.80 | 3.00 |
| E1 | 1.45 | 1.60 | 1.75 |
| L | 0.30 | 0.38 | 0.55 |
| L1 | 0.25 REF | | |
| e | 0.95 BSC. | | |
| e1 | 1.90 BSC. | | |
| α | 0° | - | 8° |

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Ordering Information

The Part No. Guide is for reference only. To customize and build an exact part number, use the TQC [Part Number Generator](#).

TQC2019BA-S2-18E -125 .000325D

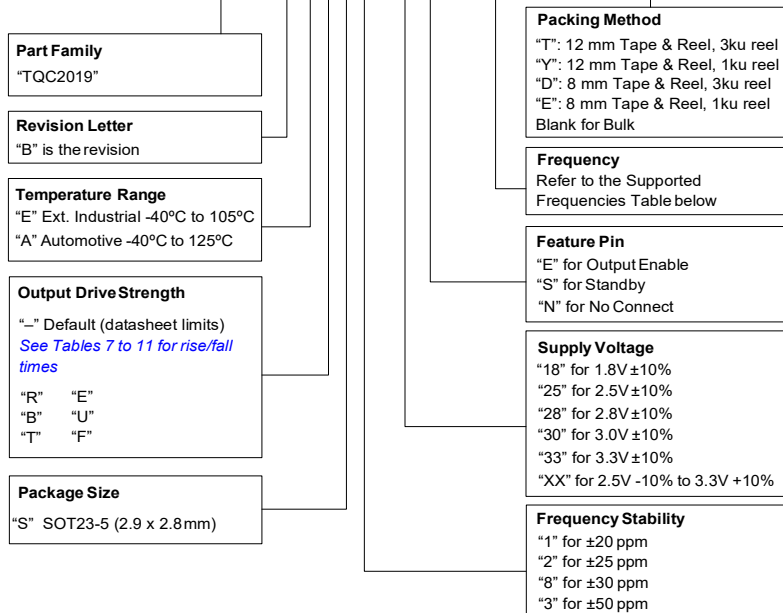


Table 14. List of Supported Frequencies^[13, 14]

| Frequency Range (-40 to +105°C or -40 to +125°C) | |
|---|----------------|
| Min. | Max. |
| 115.194001 MHz | 117.810999 MHz |
| 118.038001 MHz | 118.593999 MHz |
| 118.743001 MHz | 122.141999 MHz |
| 122.705001 MHz | 123.021999 MHz |
| 123.348001 MHz | 137.000000 MHz |

Notes:

- 13. Any frequency within the min and max values in the above table are supported with 6 decimal places of accuracy.
- 14. Please contact [TQC](#) for frequencies that are not listed in the tables above.

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Table 15. Additional Information

| Document | Description | Download Link |
|--------------------------------|--|---------------|
| Time Machine II | MEMS oscillator programmer | |
| Field Programmable Oscillators | Devices that can be programmable in the field by Time Machine II | |
| Manufacturing Notes | Tape & Reel dimension, reflow profile and other manufacturing related info | |
| Qualification Reports | RoHS report, reliability reports, composition reports | |
| Performance Reports | Additional performance data such as phase noise, current consumption and jitter for selected frequencies | |
| Termination Techniques | Termination design recommendations | |
| Layout Techniques | Layout recommendations | |

Revision History

Table 16. Datasheet Version and Change Log

| Version | Release Date | Change Summary |
|---------|--------------|---|
| 1.0 | 5/14/15 | Final Production Release. |
| 1.01 | 9/29/15 | <ul style="list-style-type: none">Revised the dimension table |

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Silicon MEMS Outperforms Quartz

Best Reliability

Silicon is inherently more reliable than quartz. Figure 1 shows a comparison with quartz technology.

Why is EpiSeal™ MEMS Best in Class:

- EpiSeal MEMS resonators are hermetically vacuum-sealed during wafer processing, which eliminates foreign particles and improves long term aging and reliability
- MEMS resonator is paired with advanced analog IC

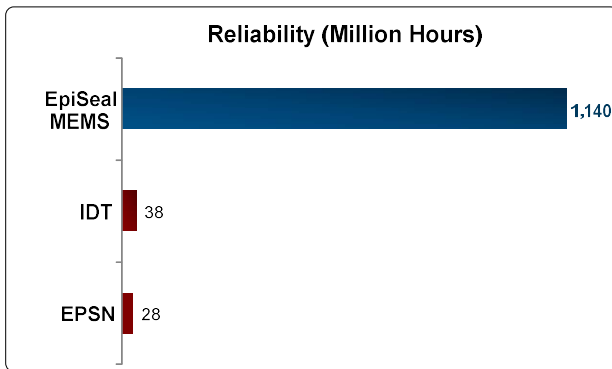


Figure 1. Reliability Comparison^[1]

Best Aging

Unlike quartz, EpiSeal MEMS oscillators have excellent long-term aging performance which is why every new EpiSeal MEMS product specifies 10-year aging.

Why is EpiSeal MEMS Best in Class:

- EpiSeal MEMS resonators are hermetically vacuum-sealed during wafer processing, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

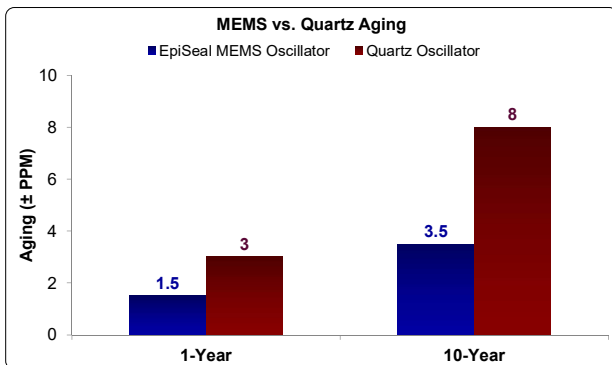


Figure 2. Aging Comparison^[2]

Best Electro Magnetic Susceptibility (EMS)

EpiSeal MEMS oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

Why is EpiSeal MEMS Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

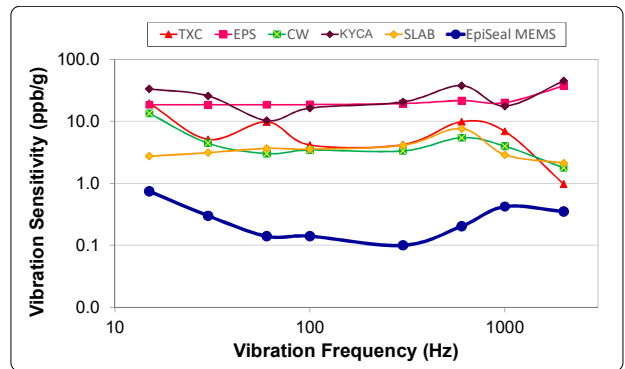


Figure 3. Electro Magnetic Susceptibility (EMS)^[3]

Best Power Supply Noise Rejection

EpiSeal MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

Why is EpiSeal MEMS Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- MEMS resonator is paired with advanced analog CMOS IC

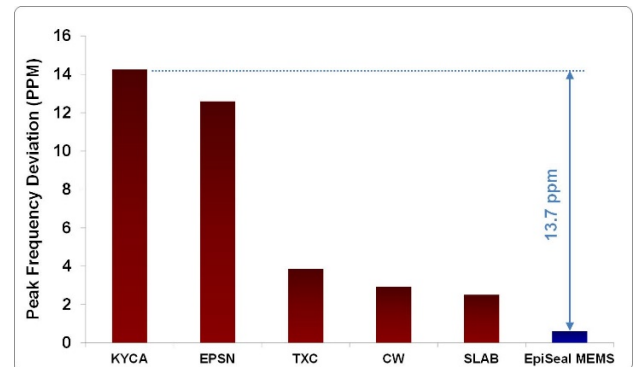


Figure 4. Power Supply Noise Rejection^[4]

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Best Vibration Robustness

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

Why is EpiSeal MEMS Best in Class:

- The moving mass of MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

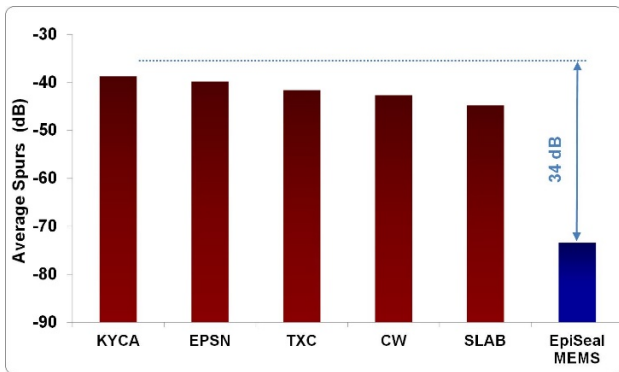


Figure 5. Vibration Robustness^[5]

Best Shock Robustness

EpiSeal MEMS oscillators can withstand at least 50,000g shock. They maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

Why is EpiSeal MEMS Best in Class:

- The moving mass of MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

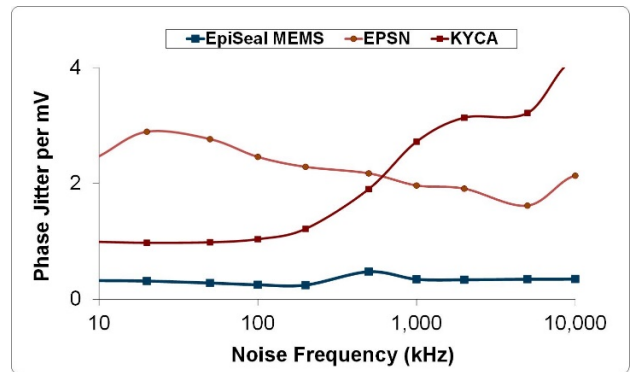


Figure 6. Shock Robustness^[6]

Figure labels:

- TXC = TXC
- Epson = EPSN
- Connor Winfield = CW
- Kyocera = KYCA
- SiLabs = SLAB
- TQC = EpiSeal MEMS

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Notes:

1. Data source: Reliability documents of named companies.
2. Data source: TQC and quartz oscillator devices datasheets.
3. Test conditions for Electro Magnetic Susceptibility (EMS):
 - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
 - Field strength: 3V/m
 - Radiated signal modulation: AM 1 kHz at 80% depth
 - Carrier frequency scan: 80 MHz – 1 GHz in 1% steps
 - Antenna polarization: Vertical
 - DUT poTQCion: Center aligned to antenna

Devices used in this test:

| Label | Manufacturer | Part Number | Technology |
|--------------|-----------------|-----------------------------|--|
| EpiSeal MEMS | TQC | TQC9120AC-1D2-33E156.250000 | MEMS + PLL |
| EPSN | Epson | EG-2102CA156.2500M-PHPAL3 | Quartz, SAW |
| TXC | TXC | BB-156.250MBE-T | Quartz, 3 rd Overtone |
| CW | Conner Winfield | P123-156.25M | Quartz, 3 rd Overtone |
| KYCA | AVX Kyocera | KC7050T156.250P30E00 | Quartz, SAW |
| SLAB | SiLab | 590AB-BDG | Quartz, 3 rd Overtone + PLL |

4. 50 mV pk-pk Sinusoidal voltage.

Devices used in this test:

| Label | Manufacturer | Part Number | Technology |
|--------------|--------------|----------------------------|------------|
| EpiSeal MEMS | TQC | TQC8208AI-33-33E-25.000000 | MEMS + PLL |
| NDK | NDK | NZ2523SB-25.6M | Quartz |
| KYCA | AVX Kyocera | KC2016B25M0C1GE00 | Quartz |
| EPSN | Epson | SG-310SCF-25M0-MB3 | Quartz |

5. Devices used in this test:

same as EMS test stated in Note 3.

6. Test conditions for shock test:

- MIL-STD-883F Method 2002
- Condition A: half sine wave shock pulse, 500-g, 1ms
- Continuous frequency measurement in 100 μ s gate time for 10 seconds

Devices used in this test:

same as EMS test stated in Note 3.

7. Additional data, including setup and detailed results, is available upon request to qualified customer.